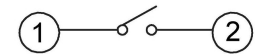


CIRCUIT DIAGRAM



SPECIFICATION

Contact Rating: 50mA,12V DC
 Contact Resistance: 100mΩ max
 Insulation Resistance: 100mΩ min.500V DC
 Dielectric Strength: 250V AC/1minute
 Travel: 0.25mm
 Operating Temp: -30°C~+85°C
 Storage Temp: -30°C~+80°C

PAPT NO	TS-1101VS-X-X-B
Operating Force	A:100gf B:160gf C:260gf
Height	H:3.5
Fixed column	A:With B:without
Keystake	A:PA46; B:Silica gel

ITEM	PAPT NAMF	TER.NO	QTY	MATERIAL	FINISHING	REMARK
⑤	Terminal	—	2	Brass (0.30t)	Plating silvering	—
④	Contact	—	1	F.ag/Sus	Natural	—
③	Base	—	1	Lcp	—	—
②	Cover	—	1	Brass	Plating Nickel	—
①	Keystake	—	1	Silica gel	—	—

DSND		DATE		SCALE: N/A	MODEL TYPE: TACT SWITCH
DWN		DATE		VIEW:	PART NO.:
CHKD		DATE		UNIT: mm/in	DWG NO.:
APPD		DATE		SIZE: A4	TS-1101VS-X-X-B
UNSPECIFIED TOLERANCES				DONG GUAN XI BANG ELECTRONIC CO., LTD	WEIGHT 1.0g
					SHEET 1/1
					REVISION A0

MARK	DESCRIPTION	DATE	REVISED	APPROVED	units: mm	tolerance:
ΔX					X.X	±0.2mm
ΔX					X.XX	±0.1mm
ΔX					X.XXX	±0.05mm
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